

Power Schottky rectifier

Features

- High current capability
- Avalanche rated
- Low forward voltage drop current
- High frequency operation

Description

This Schottky rectifier is suited for high frequency switch mode power supply.

Packaged in TO-220AB, D²PAK and I²PAK, this device is intended to be used in notebook, game station and desktop adaptors, providing in these applications a good efficiency at both low and high load.

Table 1. Device summary

$I_{F(AV)}$	2 x 20 A
V_{RRM}	100 V
T_j (max)	150 °C
V_F (typ)	0.435 V

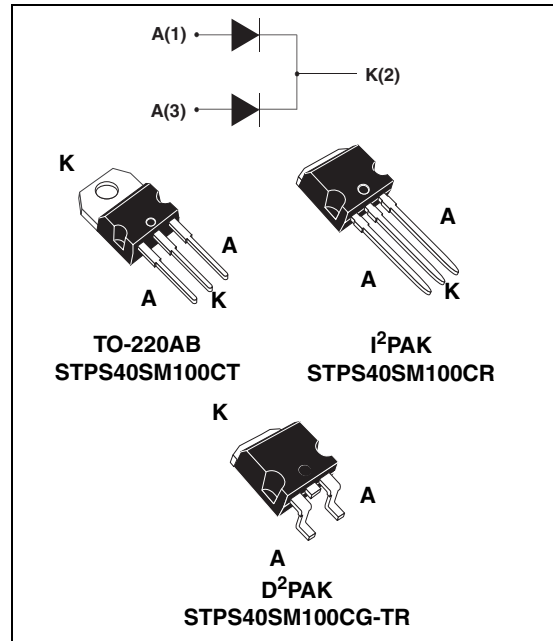
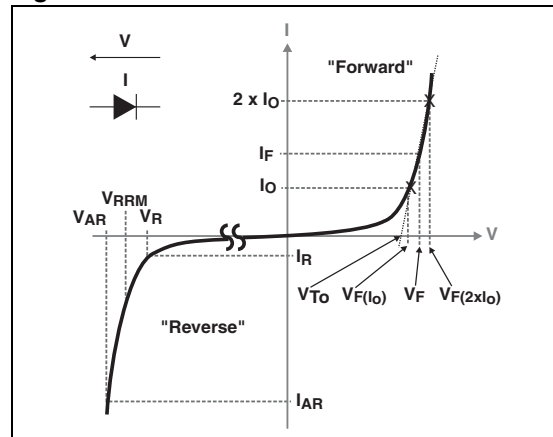


Figure 1. Electrical characteristics (a)



- a. V_{ARM} and I_{ARM} must respect the reverse safe operating area defined in [Figure 11](#). V_{AR} and I_{AR} are pulse measurements ($t_p < 1 \mu s$). V_R , I_R , V_{RRM} and V_F , are static characteristics

1 Characteristics

Table 2. Absolute ratings (limiting values)

Symbol	Parameter		Value	Unit	
V_{RRM}	Repetitive peak reverse voltage		100	V	
$I_{F(RMS)}$	Forward current rms		60	A	
$I_{F(AV)}$	Average forward current $\delta = 0.5$	$T_c = 130\text{ }^\circ\text{C}$	Per diode	20	A
		$T_c = 125\text{ }^\circ\text{C}$	Per device	40	
I_{FSM}	Surge non repetitive forward current		$t_p = 10\text{ ms}$ sinusoidal	530	A
$P_{ARM}^{(1)}$	Repetitive peak avalanche power		$t_p = 1\text{ }\mu\text{s}$ $T_j = 25\text{ }^\circ\text{C}$	18000	W
$V_{ARM}^{(2)}$	Maximum repetitive peak avalanche voltage		$t_p < 1\text{ }\mu\text{s}$ $T_j < 150\text{ }^\circ\text{C}$ $I_{AR} < 45\text{ A}$	120	V
$V_{ASM}^{(2)}$	Maximum single pulse peak avalanche voltage		$t_p < 1\text{ }\mu\text{s}$ $T_j < 150\text{ }^\circ\text{C}$ $I_{AR} < 45\text{ A}$	120	V
T_{stg}	Storage temperature range		-65 to + 175	$^\circ\text{C}$	
T_j	Maximum operating junction temperature ⁽³⁾		150	$^\circ\text{C}$	

1. For temperature or pulse time duration deratings, refer to [Figure 4.](#) and [Figure 5.](#) More details regarding the avalanche energy measurements and diode validation in the avalanche are provided in the application notes AN1768 and AN2025.

2. Refer to [Figure 11.](#)

3. $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistance

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case	Per diode	1.3	$^\circ\text{C/W}$
		Total	0.7	
$R_{th(c)}$	Coupling		0.1	

Table 4. Static electrical characteristics (per diode, at 25 °C unless otherwise specified)

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25\text{ }^\circ\text{C}$	$V_R = 70\text{ V}$		7		μA
		$T_j = 125\text{ }^\circ\text{C}$			7		mA
		$T_j = 25\text{ }^\circ\text{C}$	$V_R = 100\text{ V}$		13	45	μA
		$T_j = 125\text{ }^\circ\text{C}$			13	45	mA
$V_F^{(2)}$	Forward voltage drop	$T_j = 25\text{ }^\circ\text{C}$	$I_F = 5\text{ A}$		520		mV
		$T_j = 125\text{ }^\circ\text{C}$			435		
		$T_j = 25\text{ }^\circ\text{C}$	$I_F = 10\text{ A}$		620	700	
		$T_j = 125\text{ }^\circ\text{C}$			520	580	
		$T_j = 25\text{ }^\circ\text{C}$	$I_F = 20\text{ A}$		740	810	
		$T_j = 125\text{ }^\circ\text{C}$			605	665	

1. Pulse test: $t_p = 5\text{ ms}$, $\delta < 2\%$

2. Pulse test: $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.580 \times I_{F(AV)} + 0.0043 \times I_{F(RMS)}^2$$

Figure 2. Average forward power dissipation versus average forward current (per diode)

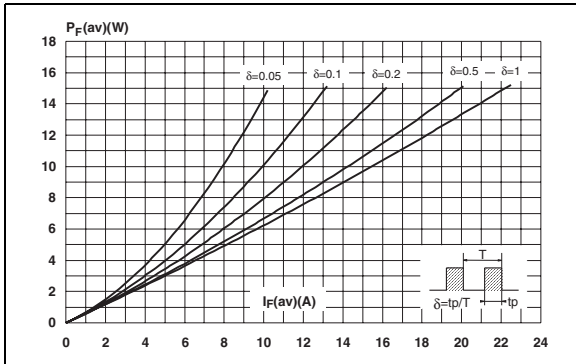


Figure 3. Average forward current versus ambient temperature ($\delta = 0.5$, per diode)

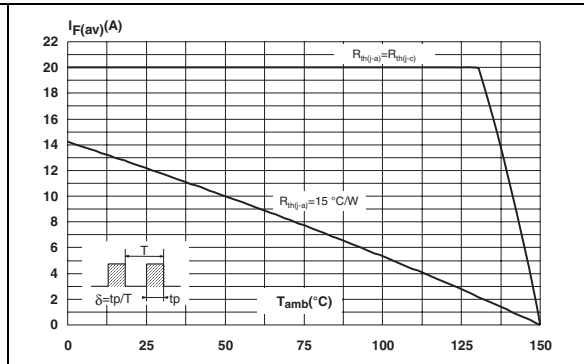


Figure 4. Normalized avalanche power derating versus pulse duration

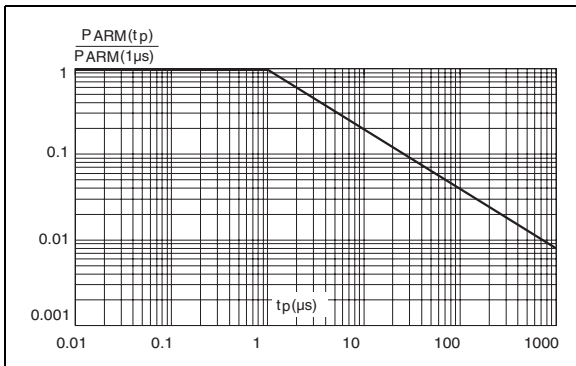


Figure 5. Normalized avalanche power derating versus junction temperature

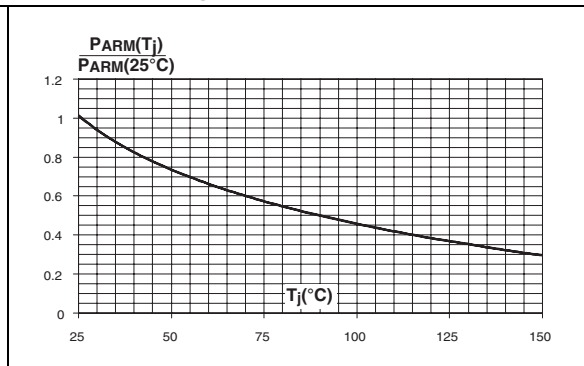


Figure 6. Non repetitive surge peak forward current versus overload duration, maximum values, per diode

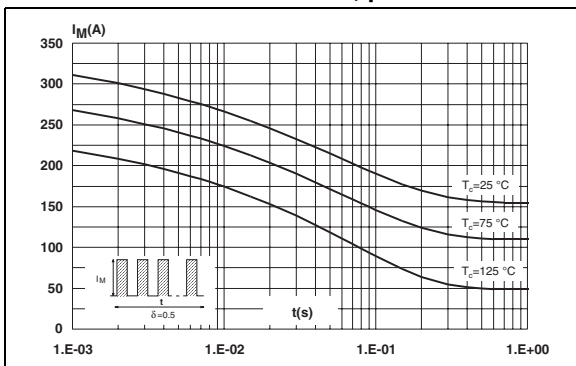


Figure 7. Relative variation of thermal impedance junction to case versus pulse duration

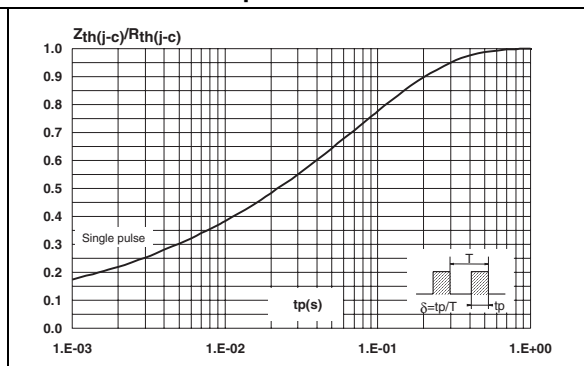


Figure 8. Reverse leakage current versus reverse voltage applied (typical values, per diode)

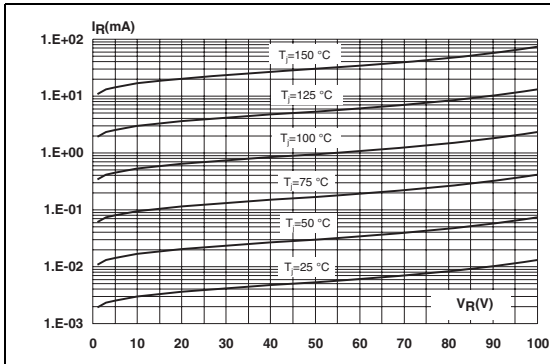


Figure 9. Junction capacitance versus reverse voltage applied (typical values, per diode)

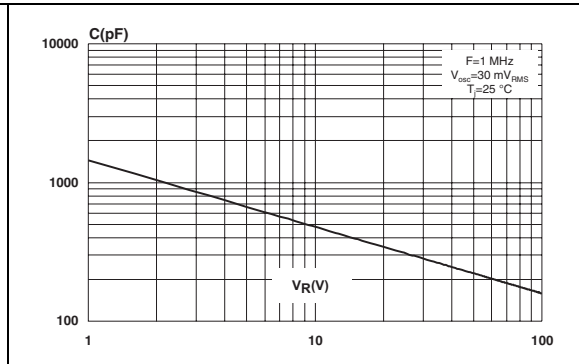


Figure 10. Forward voltage drop versus forward current (per diode)

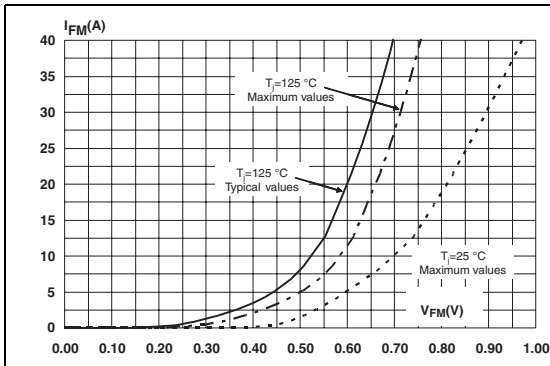
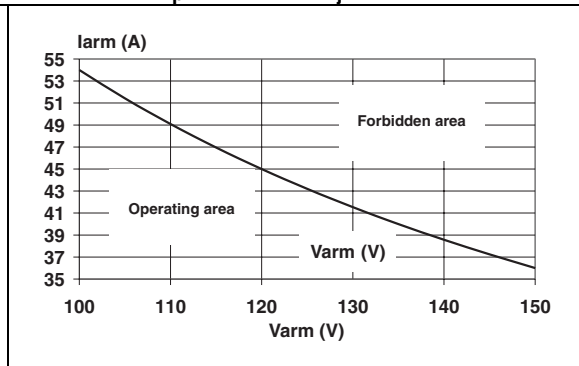


Figure 11. Reverse safe operating area ($t_p < 1\ \mu\text{s}$ and $T_j < 150^\circ\text{C}$)



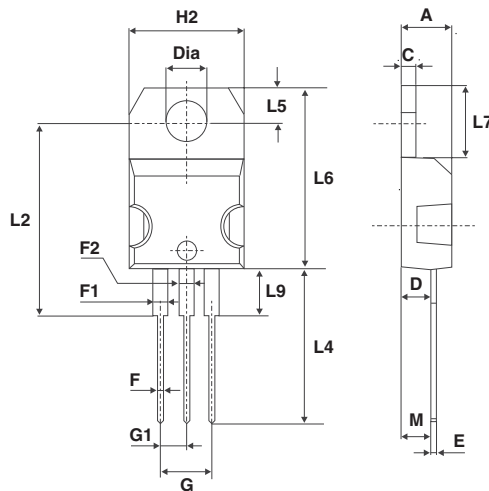
2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

Table 5. TO-220AB dimensions

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
C	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
E	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
F2	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
G1	2.40	2.70	0.094	0.106
H2	10	10.40	0.393	0.409
L2	16.4 typ.		0.645 typ.	
L4	13	14	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
M	2.6 typ.		0.102 typ.	
Diam.	3.75	3.85	0.147	0.151



Mounting (soldering) the I²PAK metal slug (heatsink) with alloy, like a surface mount device, IS NOT PERMITTED. A standard through-hole mounting is mandatory.

Table 6. I²PAK dimensions

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
A1	2.40	2.72	0.094	0.107
b	0.61	0.88	0.024	0.035
b1	1.14	1.70	0.044	0.067
c	0.49	0.70	0.019	0.028
c2	1.23	1.32	0.048	0.052
D	8.95	9.35	0.352	0.368
e	2.40	2.70	0.094	0.106
e1	4.95	5.15	0.195	0.203
E	10	10.40	0.394	0.409
L	13	14	0.512	0.551
L1	3.50	3.93	0.138	0.155
L2	1.27	1.40	0.050	0.055

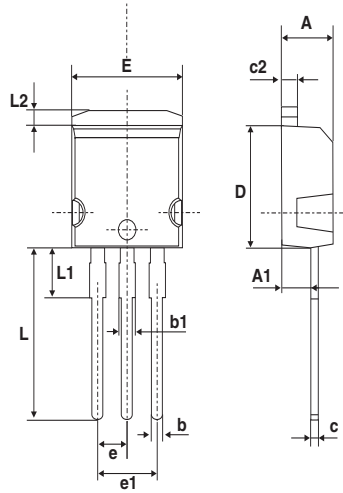
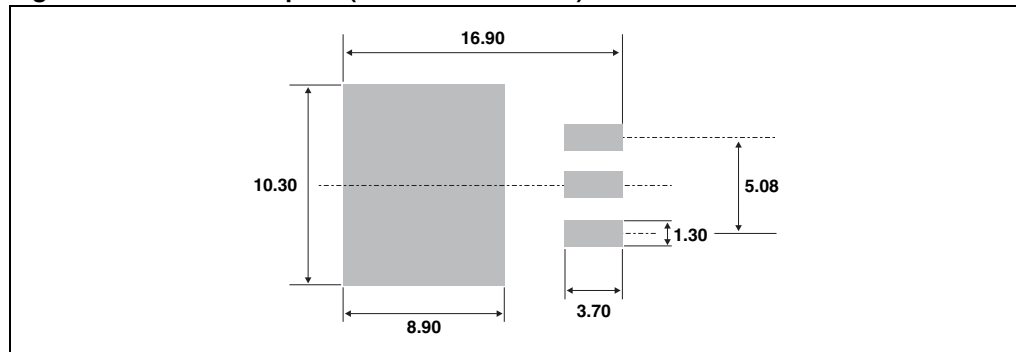


Table 7. D²PAK dimensions

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
A1	2.49	2.69	0.098	0.106
A2	0.03	0.23	0.001	0.009
B	0.70	0.93	0.027	0.037
B2	1.14	1.70	0.045	0.067
C	0.45	0.60	0.017	0.024
C2	1.23	1.36	0.048	0.054
D	8.95	9.35	0.352	0.368
E	10.00	10.40	0.393	0.409
G	4.88	5.28	0.192	0.208
L	15.00	15.85	0.590	0.624
L2	1.27	1.40	0.050	0.055
L3	1.40	1.75	0.055	0.069
M	2.40	3.20	0.094	0.126
R	0.40 typ.		0.016 typ.	
V2	0°	8°	0°	8°

Figure 12. D²PAK footprint (dimensions in mm)



3 Ordering information

Table 8. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS40SM100CT	PS40SM100CT	TO-220AB	2.2 g	50	Tube
STPS40SM100CR	PS40SM100CR	I ² PAK	1.49 g	50	Tube
STPS40SM100CG	PS40SM100CG	D ² PAK	1.48 g	50	Tube
STPS40SM100CG-TR	PS40SM100CG	D ² PAK	1.48 g	1000	Tape and reel

4 Revision history

Table 9. Document revision history

Date	Revision	Changes
25-Mar-2009	1	First issue.
15-Apr-2010	2	Updated package graphics for TO-220AB on front page and in Table 5 .

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